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She is author or co-author of about 43 technical reports registered in the Internal STMicroelectronics Library, 70 peer reviewed papers, 2 book chapters, and 6 issued US patents (6 US Patent Applications pending). She has been invited to 12 conferences and has about 1300 citations. S. M. S. Privitera has also participated in several committees and organized conferences and several symposia, one as leading organizer at the Materials Research Society (MRS) Spring Meeting in Phoenix, USA.

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